

Metal telluride nanosheets by scalable solid lithiation and exfoliation

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Transition metal tellurides (TMTs) have been ideal materials for exploring exotic properties in condensed-matter physics, chemistry and materials science^{1–3}. Although TMT nanosheets have been produced by top-down exfoliation, their scale is below the gram level and requires a long processing time, restricting their effective application from laboratory to market^{4–8}. We report the fast and scalable synthesis of a wide variety of MTe_2 ($\text{M} = \text{Nb}, \text{Mo}, \text{W}, \text{Ta}, \text{Ti}$) nanosheets by the solid lithiation of bulk MTe_2 within 10 min and their subsequent hydrolysis within seconds. Using NbTe_2 as a representative, we produced more than a hundred grams (108 g) of NbTe_2 nanosheets with 3.2 nm mean thickness, 6.2 μm mean lateral size and a high yield (>80%). Several interesting quantum phenomena, such as quantum oscillations and giant magnetoresistance, were observed that are generally restricted to highly crystalline MTe_2 nanosheets. The TMT nanosheets also perform well as electrocatalysts for lithium–oxygen batteries and electrodes for microsupercapacitors (MSCs). Moreover, this synthesis method is efficient for preparing alloyed telluride, selenide and sulfide nanosheets. Our work opens new opportunities for the universal and scalable synthesis of TMT nanosheets for exploring new quantum phenomena, potential applications and commercialization.

TMTs have been investigated less thoroughly than other 2D materials despite being some of the most fascinating materials for both fundamental research and industrial applications^{9–11}. Several TMTs, such as WTe_2 and MoTe_2 , have been recently investigated for a variety of quantum phenomena, including an extremely large magnetoresistance, topologically nontrivial phases and coupled ferroelectricity and superconductivity^{12–14}. 2H-MoTe_2 nanosheets have great potential as electrocatalysts for the efficient production of H_2O_2 and green H_2 (refs. 15,16). To promote the use of TMT nanosheets from a laboratory to an industrial scale, safe, reproducible and scalable synthesis techniques must be developed^{4,5}.

Exfoliation techniques, such as ball milling, liquid-phase exfoliation, along with intercalation-based exfoliation, have been used as ‘top-down’ methods for mass producing nanosheets from their bulk counterparts^{6–8,17–22}. Ball milling and liquid exfoliation are not easily scalable because they produce nanosheets with a sub-micrometre lateral size and poor repeatability^{7,17}. Intercalation-based exfoliation, on the other hand, by intercalating guest ions or molecules between the layers of bulk crystals driven by electrochemical or chemical methods and delaminating the crystals into large few-layer and monolayer

nanosheets with solution processability and a low energy cost, is a more promising approach for producing high-quality TMT nanosheets¹⁹. However, electrochemical intercalation-based exfoliation requires the use of a single-crystal electrode or coating powders on a conductive substrate, limiting the production scale and requiring cumbersome steps^{6,18,21}. Chemical intercalation-based exfoliation has potential for the scalable production of nanosheets from their bulk powders. Unfortunately, commonly used organolithium as an intercalation reagent is highly explosive in ambient atmosphere, requires strictly controlled laboratory conditions and is difficult to intercalate into TMT crystals because of their strong interlayer binding energy^{22–24}. At present, the production of TMT nanosheets remains below the gram scale and requires a long processing time of more than 30 min using existing exfoliation methods. Compared with solvent chemical intercalation-based exfoliation, solid-state intercalation has great advantages in safety and scalability²⁵. Tetrahydroborates are promising reducing agents and are stable enough to be handled in air for a short duration²⁶. Therefore, they can be exploited for the solid lithiation and exfoliation of a large quantity of TMTs into high-quality TMT nanosheets.

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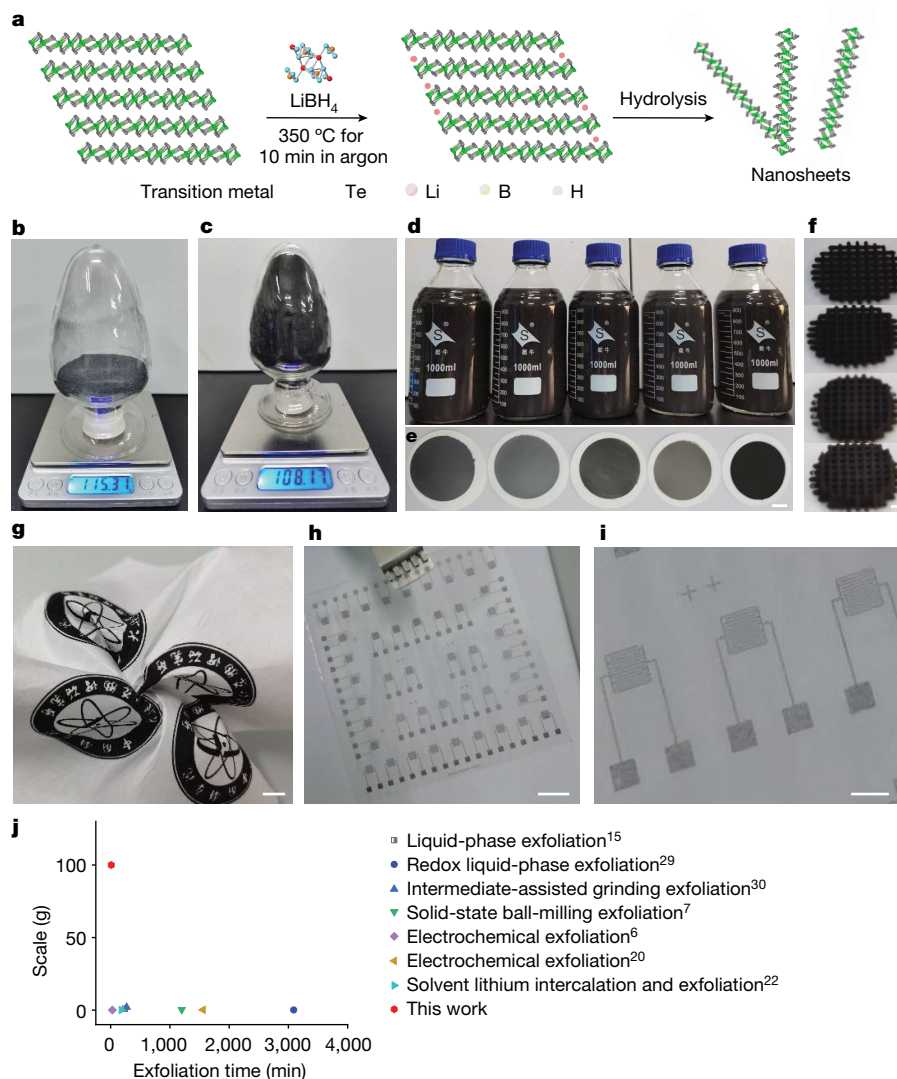


Fig. 1 | Synthesis of 2D TMT nanosheets and the applications of TMT inks.

a, Illustration of the solid lithiation and exfoliation of TMT nanosheets. **b,c**, Photographs of bulk NbTe₂ crystals (**b**) and NbTe₂ nanosheets (**c**). **d**, Photograph of NbTe₂ water dispersions in 1-L bottles with a concentration of 1 mg mL⁻¹. **e**, Photographs of MoTe₂, WTe₂, NbTe₂, TaTe₂ and TiTe₂ films (from left to right) with a diameter of 47 mm. Scale bar, 10 mm. **f**, 3D-printed scaffold with a microlattice pattern created using NbTe₂ nanosheet ink. Scale bar, 1 mm. **g**, Distorted and folded white non-woven fabric with a screen-printed DICP

logo using NbTe₂ nanosheet ink. Scale bar, 10 mm. **h**, Array of NbTe₂-based interdigital microelectrodes on glass, fabricated by photolithography. Scale bar, 10 mm. **i**, Enlarged view of **h**. Scale bar, 2 mm. **j**, Exfoliation time versus production scale of TMT nanosheets prepared by different methods, including liquid-phase exfoliation, electrochemical exfoliation, grinding exfoliation, ball-milling exfoliation, solvent lithium intercalation and exfoliation, and solid lithiation and exfoliation. Superscript numbers are references.

We report an ultrafast, repeatable and hundred-gram-scale production method to synthesize MoTe₂, WTe₂, NbTe₂, TaTe₂ and TiTe₂ nanosheets by solid lithiation and exfoliation. The synthesis of TMT nanosheets using lithium intercalation and hydrolysis is illustrated in Fig. 1a. First, bulk TMT crystals were prepared by chemical vapour transport (CVT) (Supplementary Fig. 1). A mixture of bulk TMT crystals and LiBH₄ was then heated at 350 °C for 10 min in an argon atmosphere to complete the solid-state lithium intercalation, which is much faster than the solvothermal process (3 h)²². X-ray diffraction (XRD) patterns of the lithiated intermediate of Li_xMTe₂ (*x* is the molar ratio of LiBH₄ to MTe₂ in the prepared mixture) showed that the new (002)* peak shifted to a lower angle compared to the bulk MTe₂ crystal, indicating an increased interlayer spacing caused by lithium-ion intercalation²⁷ (Supplementary Fig. 2). The lithiated material was then exfoliated into nanosheets by hydrolysis. Taking NbTe₂ as an example, lithiated NbTe₂ powder was hydrolysed into NbTe₂ nanosheets by adding distilled water, resulting in the formation of a black colloidal suspension within

seconds, which exhibits the Tyndall effect (Extended Data Fig. 1). This method is general and can be used for producing a wide range of TMT nanosheets, including MoTe₂, WTe₂, NbTe₂, TaTe₂ and TiTe₂.

To optimize the exfoliation process, the optimum molar ratio of LiBH₄ to TMT bulk crystals and the time of lithium intercalation were investigated. In general, TMT crystals were found to be unstable when the duration of lithium intercalation was long. For MoTe₂, WTe₂, NbTe₂, TaTe₂ and TiTe₂, the decomposition of the nanosheets became more severe as the lithium intercalation time was increased from 1 to 6 h (Supplementary Fig. 3). The decomposition products were Te nanobelts (Extended Data Fig. 2), which may be formed in two steps according to the following equations²⁸: (1) MTe₂ + LiBH₄ → Li₂Te + M + B + H₂ and (2) Li₂Te + H₂O → Te + H₂ + LiOH. The nanobelts were found on VTe₂ and ZrTe₂ nanosheets after only 10 min of intercalation (Supplementary Figs. 4 and 5). The exfoliation yield increased with the molar ratio (*x*) of LiBH₄ to TMT bulk crystals from 0.1 to 0.75 (Extended Data Fig. 3). It was found that *x* ranging from 0.75 to 1 was

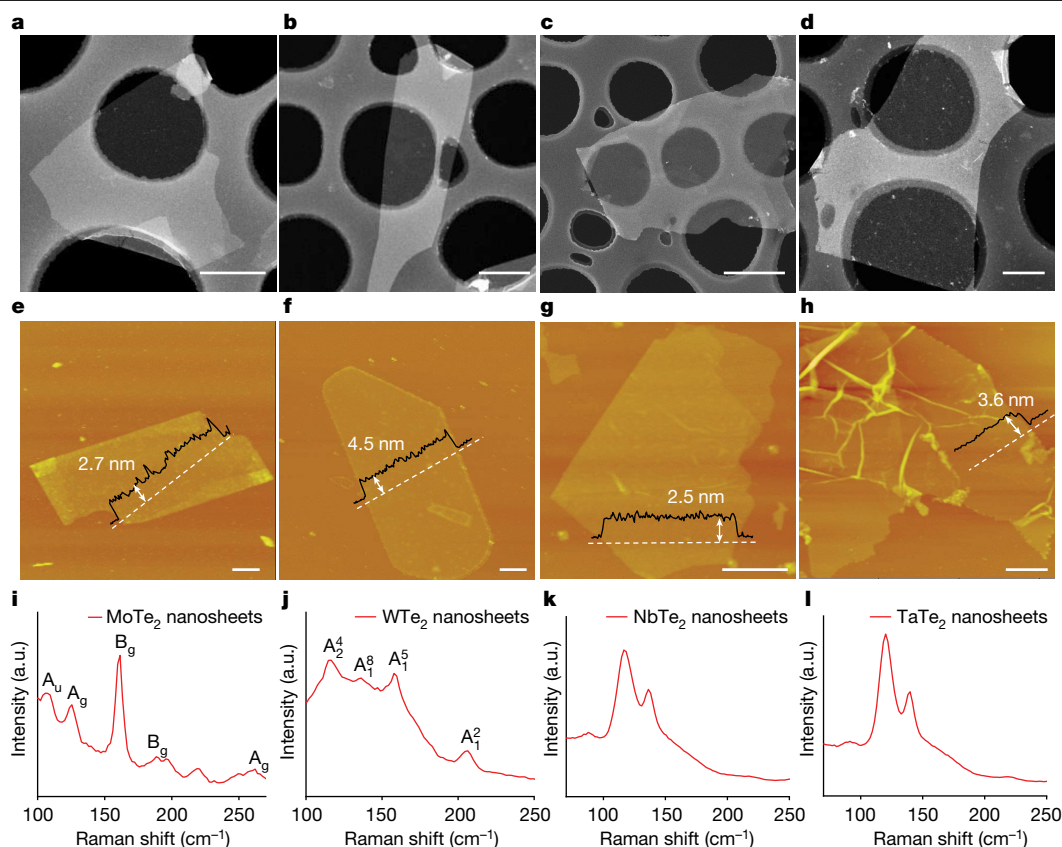


Fig. 2 | Morphology and Raman characterizations of TMT nanosheets. **a–d**, SEM images. Scale bars, 1 μm . **e–h**, AFM images. Scale bars, 0.5 μm . **i–l**, Raman spectra. MoTe₂, WTe₂, NbTe₂ and TaTe₂ nanosheets shown from left to right. a.u., arbitrary units.

suitable for achieving high exfoliation yields of more than 60% for MoTe₂, 50% for WTe₂, 80% for NbTe₂, 80% for WTe₂ and 40% for TiTe₂. Using NbTe₂ as an example, we demonstrated the scaled-up production of 108 g of NbTe₂ nanosheet powder (Fig. 1b,c) and was readily dispersible in an aqueous medium with a concentration of 1 mg mL⁻¹ (Fig. 1d). Films of MoTe₂, WTe₂, NbTe₂, TaTe₂ and TiTe₂ nanosheets were easily prepared from the corresponding colloidal dispersions by vacuum filtration (Fig. 1e). The NbTe₂ nanosheet powder could also be readily processed into various inks. Scaffolds with microlattice patterns, a DICP (Dalian Institute of Chemical Physics) logo on flexible non-woven fabric and paper and high-resolution interdigital microelectrodes were fabricated by 3D printing, screen printing and photolithography, respectively, paving the way for versatile applications (Fig. 1f–i and Supplementary Fig. 6). Figure 1j shows comparisons of the efficiency and scalability of solid lithiation and exfoliation for producing TMT nanosheets with other exfoliation methods, such as liquid-phase exfoliation, intermediate-assisted grinding exfoliation, solid-state ball-milling exfoliation, electrochemical molecular intercalation and exfoliation, and solvent lithium intercalation and exfoliation^{6,7,15,20,22,29,30} (Supplementary Table 1). Our method has the shortest processing time of 10 min and the best scalability (hundred-gram range) among all methods. To the best of our knowledge, our exfoliation method is the only one that allows production on such a large scale in only 10 min.

The morphology and size distribution of the 2D TMT nanosheets were examined by scanning electron microscopy (SEM) (Fig. 2a–d and Supplementary Fig. 7). All of the TMT nanosheets were found to be thin with a micrometre-scale lateral size. From statistical analysis (Supplementary Fig. 8), the mean lateral size of the nanosheets was measured to be 3.5 μm for MoTe₂, 2.9 μm for WTe₂, 6.2 μm for NbTe₂,

3.1 μm for TaTe₂ and 1.6 μm for TiTe₂. These values are much larger than the sub-micrometre lateral sizes of TMT nanosheets prepared by liquid-phase or solid-state ball-milling exfoliation^{7,17}. Atomic force microscopy (AFM) images show that the as-prepared TMT nanosheets are thin and have a flat morphology. MoTe₂, WTe₂, NbTe₂, TaTe₂ and TiTe₂ nanosheets have average thicknesses of 5.8, 4.9, 3.2, 5.0 and 9.8 nm, respectively (Fig. 2e–h and Supplementary Figs. 9 and 10). Notably, the exfoliation yield (40–80%) and large lateral size (>2 μm) with a narrow thickness distribution (1–14 nm) are also competitive with other exfoliation methods (Supplementary Table 1). The Raman spectra of TMT nanosheets are consistent with those in previous reports^{10,31–33} (Fig. 2i–l and Supplementary Fig. 11).

X-ray photoelectron spectroscopy (XPS) differentiates the surface bonding features of the TMT nanosheets from those of the corresponding bulk crystals. High-resolution XPS spectra of Mo 3d, W 4f, Nb 3d, Ta 4f, Ti 2p and Te 3d are given in Supplementary Figs. 12–16. Large integrated areas are observed under the Te–O peak around 576.1 eV and the Te 3d peak around 586.4 eV for all of the nanosheets, indicating surface oxidation, which is consistent with what is seen in liquid-exfoliated TMT nanosheets^{34,35} (Supplementary Figs. 12–16). Furthermore, elemental analysis by energy-dispersive spectrometry (EDS) shows that the molar ratios of tellurium to the metal in MoTe₂ and NbTe₂ are 1.94 and 1.85, respectively, which are close to the expected stoichiometric ratio of 2. However, WTe₂, TaTe₂ and TiTe₂ nanosheets have non-stoichiometric molar ratios of 2.53, 2.42 and 2.39, respectively, possibly caused by Te-rich clusters on the surface of the nanosheets that may contribute a larger amount of elemental Te (Supplementary Figs. 17 and 18).

The crystal structures and crystallinity of the TMT nanosheets were characterized by transmission electron microscopy (TEM). A quasi-1D structure of zigzag chains in MoTe₂ and WTe₂ nanosheets

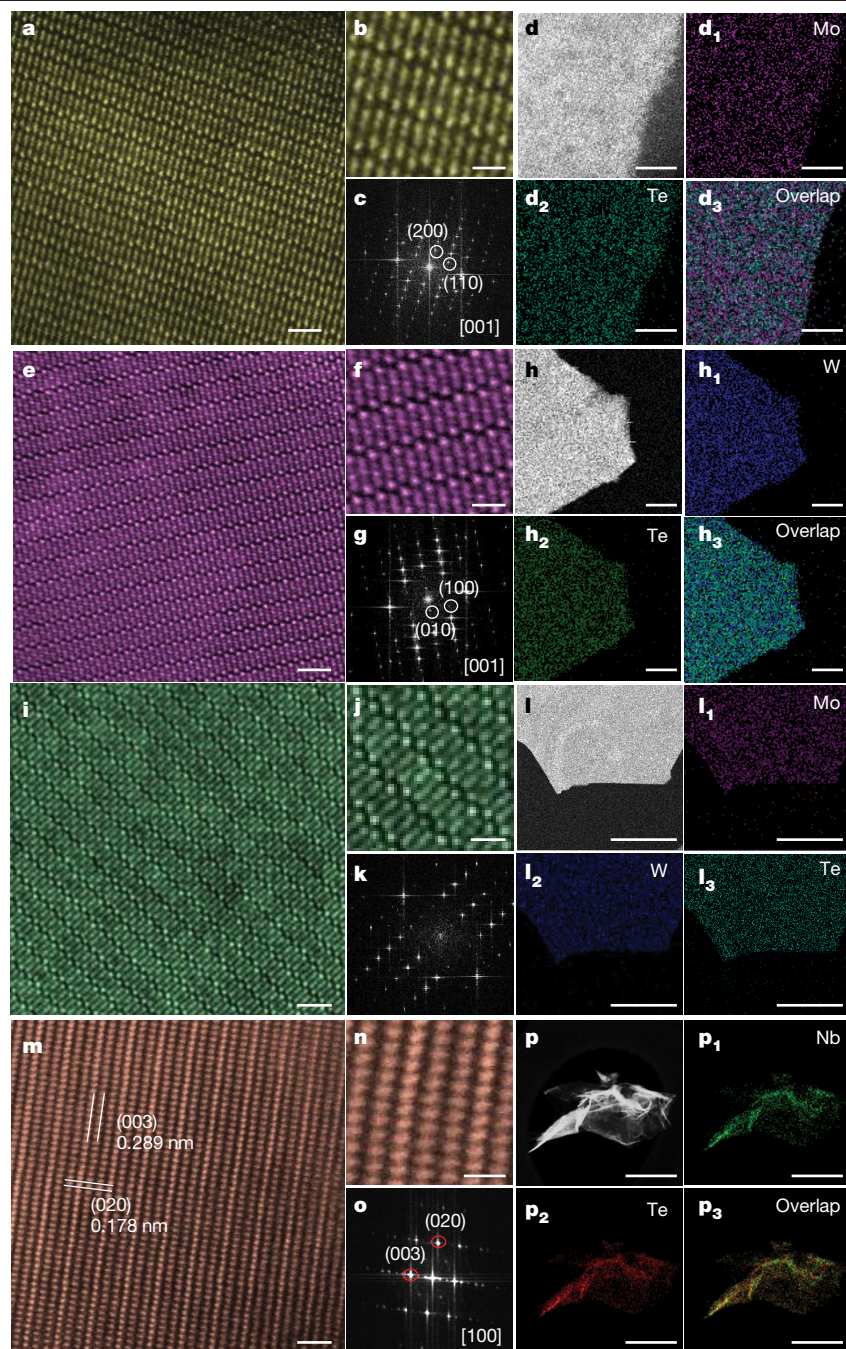


Fig. 3 | Structural characterizations of MoTe₂, WTe₂, Mo_{0.5}W_{0.5}Te₂ and NbTe₂ nanosheets. a, e, i, m, Atomic-resolution HAADF-STEM images. Scale bars, 1 nm. b, f, j, n, Magnified HAADF-STEM images. Scale bars, 0.5 nm. c, g, k, o, Corresponding FFT patterns of MoTe₂, WTe₂, Mo_{0.5}W_{0.5}Te₂ and NbTe₂, respectively. d, HAADF-STEM image and EDS elemental maps (d₁–d₃) of Mo, Te and mixed Mo

and Te, respectively. Scale bars, 5 nm. h, HAADF-STEM image and EDS elemental maps (h₁–h₃) of W, Te and mixed W and Te, respectively. Scale bars, 100 nm. l, HAADF-STEM image and EDS elemental maps (l₁–l₃) of Mo, W and Te, respectively. Scale bars, 1 μm. p, HAADF-STEM image and EDS elemental maps (p₁–p₃) of Nb, Te and mixed Nb and Te, respectively. Scale bars, 0.5 μm.

was observed in atomic high-angle annular dark-field scanning TEM (HAADF-STEM) images and the rectangular reciprocal lattices shown in fast Fourier transform (FFT) images confirm the 1T' and T_d phases and their single-crystal nature³⁶ (Fig. 3a–c, e–g). Also, a single-crystal phase with a representative zigzag chain atomic structure was observed in a Mo_{0.5}W_{0.5}Te₂ nanosheet (Fig. 3i–k). The 1T phase of NbTe₂ was verified by atomically resolved STEM and FFT images, showing dominant (003) and (020) planes with a lattice spacing of 0.289 and 0.178 nm, respectively³² (Fig. 3m–o). Energy-dispersive X-ray spectroscopy maps confirm the uniform distribution of the elements in MoTe₂,

WTe₂, Mo_{0.5}W_{0.5}Te₂ and NbTe₂ nanosheets (Fig. 3d–d₃, h–h₃, l–l₃, p–p₃). TaTe₂ and TiTe₂ nanosheets with a 1T structure were characterized by HAADF-STEM (Supplementary Figs. 19 and 20).

This solid lithiation and exfoliation method can be generalized to prepare many alloyed tellurides, such as Nb_{0.5}Ta_{0.5}Te₂, NbSeTe and Mo(SseTe)₂. It is also useful for exfoliating selenide nanosheets (MoSse, TaSse, Mo_{0.5}Nb_{0.5}Se₂, (MoNbTa)Se₂, In₂Se₃, MoSe₂, TaSe₂) and sulfide nanosheets (Mo_{0.5}Ta_{0.5}S₂, Ta_{0.5}Re_{0.5}S₂, (MoWTa)S₂, (TiZrHf)S₂, TaS₂). The detailed characterizations of these exfoliated nanosheets are presented in Extended Data Figs. 4 and 5 and Supplementary Figs. 21–48.

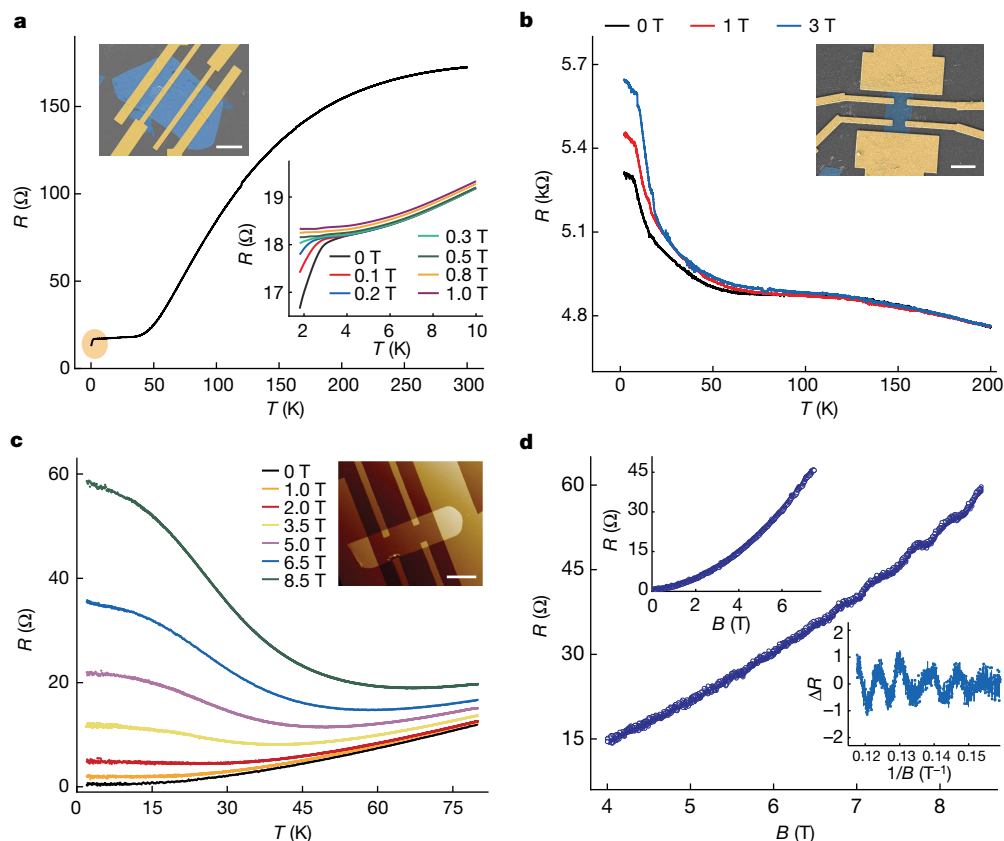


Fig. 4 | Transport properties of exfoliated MoTe₂ and WTe₂ nanosheets.

a, Resistance of 17.2-nm-thick MoTe₂ as a function of temperature at zero magnetic field. Upper inset, false-coloured SEM image of a four-terminal device. Scale bar, 5 μm . Lower inset, the resistive transition at temperatures ranging from 1.8 to 10 K in various applied magnetic field strengths. **b**, Temperature-dependent resistance of a 3.1-nm-thick MoTe₂ sample under magnetic fields of $B = 0, 1$ and 3 T. Inset, false-coloured SEM image of the

Hall-bar device. Scale bar, 2 μm . **c**, Temperature dependence of the resistance of the WTe₂ sample at various magnetic field strengths. Inset, AFM image of a fabricated WTe₂ device. Scale bar, 2 μm . **d**, Magnetoresistance data of a WTe₂ sample in the range 4–8.5 T at $T = 1.8$ K. The resistance oscillations are clearly visible at high fields. Upper inset, magnetoresistance from 0 to 7.5 T at $T = 2$ K, showing a quadratic field dependence with no sign of saturation. Lower inset, quantum oscillations that are periodic in $1/B$.

To characterize the high quality of our 2D TMT nanosheets, MoTe₂, WTe₂ and Mo_{0.5}W_{0.5}Te₂ were chosen to study their quantum transport properties. A strong thickness-dependent charge-transport behaviour was found in MoTe₂ nanosheets. Figure 4a shows the temperature dependence of the resistance for a 17.2-nm-thick MoTe₂ nanosheet at zero magnetic field. The R - T curve shows a semimetallic characteristic at high temperature. At low temperature, the resistance is gradually saturated, followed by a drop, suggesting the onset of superconductivity. A magnetic field of about 0.5 T suppresses the overall resistive transition (lower inset in Fig. 4a and Supplementary Fig. 49). An incomplete and broad transition may be related to the inhomogeneity and defects within the nanosheets. $T_{\text{c,onset}}$ is about 3 K, which is an order of magnitude larger than that of the bulk MoTe₂ (0.25 K) and comparable with that of chemical vapour deposition (CVD)-grown 2D crystals^{36,37}. After three months of storage in vacuum, the samples still maintain their metallic features (Supplementary Fig. 50), showing the high device stability of the 2D MoTe₂ prepared by this method.

We also found strong thickness-dependent electronic states in MoTe₂. Figure 4b shows the temperature dependence of the resistance for a 3.1-nm-thick sample at 0, 1 and 3 T. In contrast to thicker nanosheets, the resistive transition occurs in three stages as the temperature is reduced: at high temperatures (>150 K), the resistance increases slowly and then reaches a plateau from 150 to 50 K. Below about 50 K, a noticeable upturn is seen in $R(T)$, which becomes more pronounced with increasing magnetic field. The resistive transition obtained from another sample with a thickness of 8.4 nm has a non-monotonic temperature dependence, indicating an intermediate transition (Supplementary

Fig. 51). These results indicate that a decrease of thickness triggers competition between metallic and insulating behaviours in these lithium intercalation-exfoliated MoTe₂ nanosheets. This thickness-dependent magnetotransport behaviour was also found in an exfoliated Mo_{0.5}W_{0.5}Te₂ nanosheet (Extended Data Fig. 6). The temperature changes of carrier density (n_{c}) and Hall mobility (μ_{H}) show a kink-like feature around 50 K and 150 K (Supplementary Figs. 52 and 53 and Supplementary Table 2), which are the same characteristic temperatures as for the resistive transition. Similar behaviour has been reported previously in a MoTe₂ single crystal, which was attributed to the reconstruction of the Fermi surface owing to a thermally driven Lifshitz transition or structural phase transition related to different order topological features^{38,39}. Other possibilities are the defect-induced disorder effect, in particular for thin TMT nanosheets⁴⁰, or that solid-state intercalation induces a phase domain-wall structure⁴¹. The carrier density of MoTe₂ synthesized using our method is comparable or 1–2 orders of magnitude larger than those of mechanically exfoliated samples, suggesting the charge-carrier doping of the intercalated MoTe₂ nanosheets^{14,36,42–45} (Supplementary Fig. 54). Further experimental and theoretical studies are needed to understand the influence of the thickness on the phase transitions in 2D TMT nanosheets, and the synthesis strategy reported here may aid that pursuit.

In Fig. 4c, we show the temperature dependence of the resistance of a WTe₂ nanosheet, measured at various magnetic fields. The residual resistivity ratio ($\rho_{300\text{K}}/\rho_{2\text{K}}$) at zero magnetic field is around 200, indicating the high crystallinity of the nanosheets. When a perpendicular magnetic field was applied, the R - T curves showed a field-driven

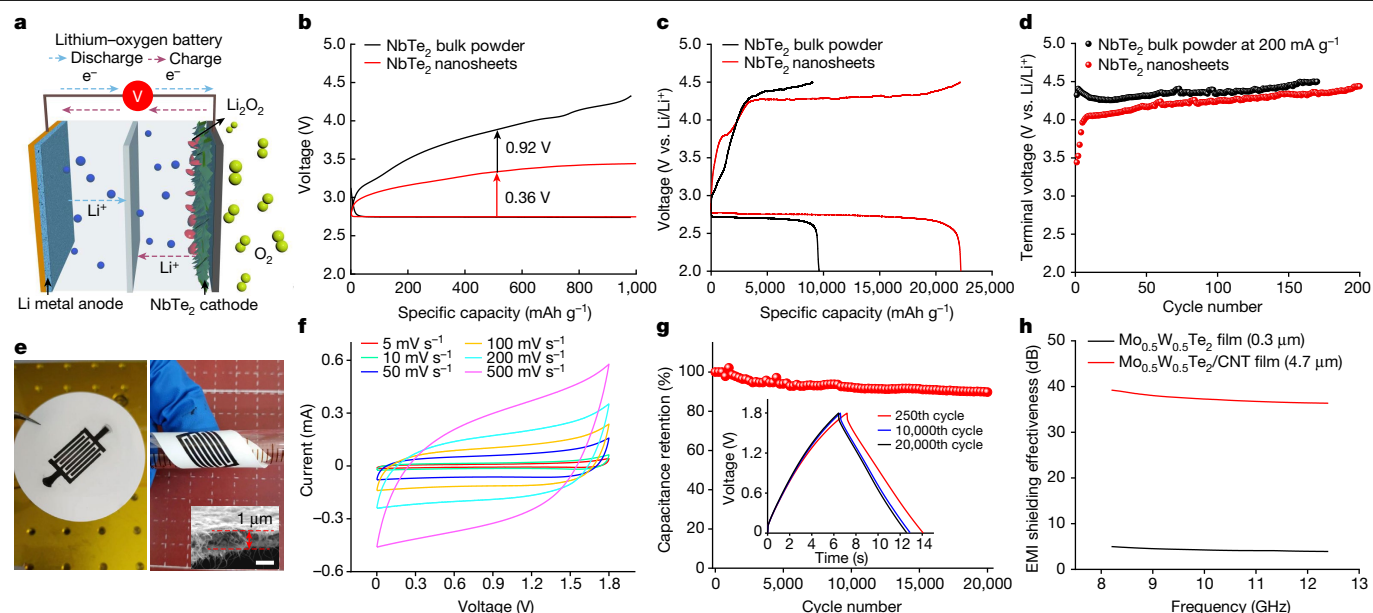


Fig. 5 | Applications of TMT nanosheets produced by solid lithiation and exfoliation. **a**, Schematic of Li–O₂ batteries. **b**, Discharge–charge profiles of 2D NbTe₂ nanosheet and NbTe₂ bulk powder cathodes for Li–O₂ batteries under a limited capacity of 1,000 mAh g^{−1} at a current density of 100 mA g^{−1}. **c**, The first discharge–charge profiles of NbTe₂ nanosheet and NbTe₂ bulk powder cathodes for Li–O₂ batteries obtained at 100 mA g^{−1}. **d**, Terminal discharge voltage versus cycle number of NbTe₂ nanosheet- and NbTe₂ bulk powder-based Li–O₂ batteries at 200 mA g^{−1}. **e**, Optical image of MSCs fabricated on a cellulose film in the flat

(left) and bent (right) states. Inset, cross-sectional SEM image of the NbTe₂ film with a thickness of 1 μm. Scale bar, 1 μm. **f**, **g**, Electrochemical performance of 2D NbTe₂ nanosheet-based MSCs. **f**, Cyclic voltammetry curves of NbTe₂ nanosheet-based MSCs in an electrolyte of EMIMBF₄ in acetonitrile (EMIMBF₄/ACN). **g**, Long-term cycling stability of NbTe₂ nanosheet-based MSCs in an EMIMBF₄/ACN electrolyte. Inset, galvanostatic charge/discharge profiles of the 250th, 10,000th and 20,000th cycles. **h**, EMI shielding performance of Mo_{0.5}W_{0.5}Te₂ and Mo_{0.5}W_{0.5}Te₂/CNT films at the X-band frequency range (8.2–12.4 GHz).

transition from a metallic to insulating-like behaviour. The magnetic field dependence of the resistance at low temperatures has an expected quadratic relationship with no sign of saturation up to 7.5 T (upper inset in Fig. 4d), showing an extremely large positive magnetoresistance. Both phenomena are consistent with previous reports obtained from WTe₂ single bulk crystals, exhibiting Weyl semimetal features³⁷. Figure 4d shows the resistance as a function of the magnetic field in the range 4–8.5 T at 1.8 K. For fields larger than 6.4 T, well-resolved resistive oscillations were clearly visible, along with extremely large positive magnetoresistance. After subtracting the smooth background using a second-order polynomial fit, the oscillatory part is plotted as a function of $1/B$ in the lower inset in Fig. 4d. A clear $1/B$ periodic pattern can be observed, which is the characteristic feature of Shubnikov–de Haas (SdH) oscillations. The observation of SdH oscillations indicates the high crystallinity and homogeneity of the WTe₂ nanosheets. From the onset of SdH oscillations, we estimated the transport mobility to be $\mu \approx 1,500 \text{ cm}^2 (\text{V s})^{-1}$, comparable with mechanically exfoliated flakes from single crystals and confirming the good electrical performance of our samples for potential applicability in quantum devices.

TMT nanosheets produced by solid lithiation and exfoliation can be applied in catalysis, energy storage and electronics devices, which need a large quantity. As demonstrated, NbTe₂ nanosheets were used as robust bifunctional electrocatalysts for reversible Li₂O₂ conversion in high-performance Li–O₂ batteries and has a much lower charge potential of 0.36 V than that of NbTe₂ bulk powder (0.92 V), proving their greatly increased catalytic activity (Fig. 5a,b). As a result, an ultra-high discharge capacity of 22,212 mAh g^{−1}, excellent rate capability and long-term cycling stability of 200 cycles under current densities of 200 and 500 mA g^{−1} have been achieved for NbTe₂ nanosheet-based Li–O₂ batteries, which are much better than those using NbTe₂ bulk powder (Fig. 5c,d and Supplementary Figs. S5 and S6). Moreover, Mo_{0.5}W_{0.5}Te₂ nanosheets show good lithium storage performance with an initial specific capacity of 510 mAh g^{−1} at 0.3 C and a high rate capacity (152 mAh g^{−1}

at 3 C) (Supplementary Fig. S7). Furthermore, NbTe₂ nanosheet-based flexible MSCs have areal and volumetric capacitances of 4.8 mF cm^{−2} and 46.5 mF cm^{−3}, respectively, at 5 mV s^{−1} with a large voltage of 1.8 V in an EMIMBF₄/ACN electrolyte, as well as an excellent stability with 90% capacitance retention after 20,000 cycles (Fig. 5e–g and Supplementary Fig. S8). Also, a Mo_{0.5}W_{0.5}Te₂/carbon nanotube (CNT) film with a well-aligned, compact and nacre-like structure showed an electromagnetic interference (EMI) shielding effectiveness of more than 36.4 dB at 8.2–12.4 GHz with a thickness of only 5 μm, which satisfies common commercial EMI shielding requirements (>20 dB) and has great promise for use in future wearable and portable electronics (Fig. 5h and Supplementary Fig. S9).

In summary, we have developed a general solid lithiation and exfoliation method for the hundred-gram synthesis of high-quality TMT nanosheets that has the potential to revolutionize their commercial manufacture. Owing to their increasing prominence, new layered TMT bulk crystals are expected to be discovered in the future and this method opens the possibility for mass production of their nanosheets. Moreover, these nanosheets have excellent processability to form various inks for fabricating membranes, films, nanocomposites and heterostructures in conjunction with advanced (micro) fabrication techniques, which will accelerate fundamental research and permit their use in many areas of research involving, but not limited to, topological electronics, catalysis, energy storage and flexible electronics.

Online content

Any methods, additional references, Nature Portfolio reporting summaries, source data, extended data, supplementary information, acknowledgements, peer review information; details of author contributions and competing interests; and statements of data and code availability are available at <https://doi.org/10.1038/s41586-024-07209-2>.

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Methods

Materials

Molybdenum (99.9%), tungsten (99.9%), niobium (99%), tantalum (99.8%), titanium (99.9%), vanadium (99.9%), zirconium (99.9%) and tellurium (99.9%) were all obtained from the Tianjin Special Powder Research Institute. Lithium borohydride was obtained from Beijing Innochem Science & Technology Co., Ltd. Polyurethane (99%), ethanol (99%), acetone (99%) and carboxymethyl cellulose (99%) were obtained from Sinopharm Chemical Reagent Co., Ltd. Li_2SO_4 (99.9%), EMIMBF₄ (99.9%), acetonitrile (99.9%), polyvinylidene fluoride (99%), Ketjen black (99.9%) and N-methylpyrrolidone (99.9%) were obtained from Shanghai Aladdin Biochemical Technology Co., Ltd. and photoresist AZ4620 from MicroChemicals GmbH. They were all used without further purification.

Preparation of metal tellurides bulk powder

TMT bulk powders MTe_2 ($\text{M} = \text{Mo}, \text{W}, \text{Nb}, \text{Ta}, \text{Ti}, \text{Zr}, \text{V}$) were synthesized by the CVT method. In detail, 0.03 mol metal M and 0.06 mol Te powder were ground for 5 min in an agate mortar. The mixture was sealed in an evacuated quartz tube (diameter 1.5 cm, length 20 cm) that was placed in a muffle furnace and directly heated at a rate of 5°C min^{-1} to 900°C , at which it remained for 24 h before the furnace was allowed to cool to room temperature. To scale up the synthesis of NbTe_2 powder to the hundred-gram scale, four sealed quartz tubes with 0.009 mol metal Nb and 0.18 mol Te powder were used to grow crystals by the CVT method. Because the saturation vapour pressure of tellurides is much lower than that of sulfur, the CVT method enables the simple production of metal tellurides at the hundred-gram scale in the laboratory.

TMT nanosheets by solid lithiation and exfoliation

LiBH_4 powder and bulk TMT crystals were mixed in molar ratios (x) of 0.25, 0.5, 0.75 and 1. Because LiBH_4 powder is hygroscopic, the mixing process was performed in a glovebox in an argon atmosphere. The mixture was directly heated at 350°C in a CVD tube furnace with an argon atmosphere for different durations to complete the solid-state lithium intercalation process and form the lithium-ion intercalated TMT compound Li_xMTe_2 . The Li_xMTe_2 powder was immediately added to distilled water to form a colloidal solution, which was centrifuged at 3,000 rpm for 5 min to remove unexfoliated bulk crystals. The centrifuged solution was freeze-dried to obtain the TMT nanosheet powder. Note that the freshly prepared Li_xMTe_2 bulk crystal must be used within 12 h to avoid deintercalation. Typically, 0.001 mol LiBH_4 powder and 0.001 mol MTe_2 bulk powder were used to prepare the Li_xMTe_2 . To scale up the production, more than a hundred grams of Li_xMTe_2 can be prepared by lithium intercalation and exfoliation in a larger CVD furnace.

Preparing MTe_2 nanosheets membranes

Membranes of MTe_2 nanosheets were prepared by vacuum filtrating the colloidal dispersion through a nylon membrane (47 mm diameter, 200 nm pore size). The $\text{Mo}_{0.5}\text{W}_{0.5}\text{Te}_2/\text{CNT}$ film was prepared by vacuum filtrating a mixed dispersion of $\text{Mo}_{0.5}\text{W}_{0.5}\text{Te}_2$ (16 mg) and CNTs (4 mg).

3D printing of NbTe_2 nanosheet scaffolds

First, printable NbTe_2 inks were prepared by mixing the NbTe_2 nanosheets (1.8 g) with 4 mL of aqueous carboxymethyl cellulose binder (50 M) in a high-speed disperser for 1 h to achieve homogenization. The resulting slurry was used to print on a three-axis micropositioning stage (ZZ-221, ZhongZhi Automation Co., Ltd.) equipped with an air-powered fluid dispenser (JND983A). The NbTe_2 inks were extruded through a nozzle with a diameter of 250 μm onto a glass substrate with a printing speed of about 5 mm s^{-1} at a flow rate of 20 psi. After printing,

the printed scaffolds with microlattice patterns were freeze-dried for 2 days to remove the solvent.

Screen printing of NbTe_2 nanosheet ink

To prepare 2D NbTe_2 -based screen-printable ink, polyurethane (1 g) was initially dissolved in a dibasic ester solvent (10 mL) to form a transparent solution. Then, 2.5 mL of polyurethane solution was uniformly mixed with the exfoliated NbTe_2 nanosheets (1 g) by ball milling to form the screen-printing ink. For the printable 'DICP' logo arrays, a screen mesh (200 mesh) with the predesigned pattern was fixed on the printing table and a non-woven fabric was placed under the screen mesh. Subsequently, the NbTe_2 -based ink was rapidly screen printed onto the non-woven fabric using a blade. After drying at 60°C for 12 h, a 2D NbTe_2 -based ultraflexible pattern was achieved.

Photolithography fabrication of NbTe_2 nanosheet-based microelectrodes

The substrates (for example, glass) were cleaned by sequential washing in ethanol and deionized water for 1 h. A thin photoresist (AZ4620) was then coated on the target substrate and exposed to ultraviolet light through a photomask, forming the predesigned pattern of the microelectrodes. NbTe_2 nanosheet microelectrodes were then obtained by blade coating with a NbTe_2 slurry, followed by lift-off in acetone, assisted by ultrasonic treatment.

Material characterization

The morphology, crystal structure and thickness of the MTe_2 bulk crystals and nanosheets were characterized by SEM (JSM-7900F, JEOL), aberration-corrected TEM (JEM-ARM 300F GRAND ARM, JEOL), AFM (Multi-Mode 3D, Veeco), XRD (SmartLab, Rigaku), XPS (Escalab 250 Xi+, Thermo Fisher) and Raman spectroscopy (LabRAM HR800, HORIBA Jobin Yvon Corporation). The EMI shielding performance of the $\text{Mo}_{0.5}\text{W}_{0.5}\text{Te}_2/\text{CNT}$ film was characterized by a PAN Network Analyzer (N5222A) in the X-band frequency range (8.2–12.4 GHz).

Device fabrication and transport measurements

For device fabrication and transport measurements, the exfoliated TMT nanosheets were transferred onto SiO_2/Si substrates. After the transfer, samples with different thicknesses were selected by colour contrast under optical microscopy and small markers were deposited near the selected sample for the subsequent nanofabrication process. The electrodes were made by standard electron-beam lithography followed by electron-beam evaporation of bilayer metal Ti/Au (5/90 nm). The thickness of the nanosheets was measured by AFM. Transport measurements were mainly performed in a physical property measurement system. The resistance was measured by an alternating-current method using a standard current-biased low-frequency lock-in technique with an excitation current ranging from 100 nA to 1 μA at a frequency of 17.777 Hz.

Assembly and characterization of lithium–oxygen batteries

The as-prepared catalysts (NbTe_2 nanosheets or NbTe_2 bulk powder, 80 wt%) with polyvinylidene fluoride (10 wt%) and Ketjen black (EC-600JD, 10 wt%) were ground with several drops of N-methyl pyrrolidone to prepare a slurry and fabricate the cathodes. The battery included an as-fabricated cathode, a glass-fibre separator, 1.0 M lithium bis(trifluoromethanesulfonic)imide in tetraethylene glycol dimethyl ether as the electrolyte and a Li foil anode, which was assembled in an Ar-filled glovebox ($\text{H}_2\text{O} < 0.01$ ppm, $\text{O}_2 < 0.01$ ppm). The Li– O_2 batteries were tested as CR2032 button batteries with holes on the cathode side. The cells were tested with a Landt battery testing system (CT3001A). The current density and specific capacity were calculated using the mass of the catalyst. Cyclic voltammetry tests were conducted using a CHI760E electrochemical workstation at a scan rate of 0.1 mV s^{-1} between 2.0 and 4.5 V.

Assembly and characterization of lithium-ion batteries

Mo_{0.5}W_{0.5}Te₂ nanosheets and bulk powder electrodes were fabricated by coating an 80-wt% slurry of the active material onto a Cu foil current collector, using a 10-wt% carboxy methyl cellulose sodium binder and 10 wt% Ketjen black (ECP600JD) as the electrical conducting agent and then dried overnight at 100 °C under vacuum. CR2016 coin-type cells were assembled in a glovebox filled with Ar (H₂O < 0.1 ppm, O₂ < 0.1 ppm), using Li metal as both the counter and reference electrodes, 1 M LiPF₆ in ethylene carbonate/dimethylcarbonate/diethyl carbonate (1:1:1 by volume) with 5.0% fluoroethylene carbonate as the electrolyte and Celgard 2500 as the separators. The areal mass loading of electrode was about 1.5–2 mg cm⁻². All of the coin cells were evaluated using a Landt CT3002A battery testing system in the constant current mode between 0.1 and 2.5 V (versus Li⁺/Li) at 28 °C. Here 1 C is defined as 200 mA g⁻¹.

Assembly and characterization of MSCs

The interdigital microelectrodes of NbTe₂-based MSCs were fabricated by vacuum filtration of a dispersion mixture containing NbTe₂ (10 mg) and CNTs (2 mg) through an interdigital mask onto a polytetrafluoroethylene membrane. They were then transferred to a polyethylene terephthalate substrate and dried at room temperature. Electrolytes of Li₂SO₄ in distilled water and EMIMBF₄ in acetonitrile were coated onto the projected area of microelectrodes. The electrochemical performance was tested on a CHI760E electrochemical workstation.

Data availability

All data supporting the findings of this study are available in the paper and its Supplementary Information. Other raw data are available from

the corresponding authors on request. Source data are provided with this paper.

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Author contributions Z.-S.W., N.K. and H.-M.C. conceived and supervised the project. L.Z. conducted the production and characterization of the TMT nanosheets. Z.Y., Y.F., S.F. and D.-M.S. carried out transport measurements of the TMT nanosheet devices. Q.J. performed the XRD and XPS of the alloyed nanosheets. Y.D. characterized the Li–O₂ batteries. P.D. tested the electrochemical performance of the MSCs. Z.B. characterized the lithium batteries. J.Ma., J.Mi, S.W., Z.G. and S.Z. carried out the 3D printing, photolithography and screen printing of the NbTe₂ nanosheet ink. H.Z. characterized the EMI shielding performance of the Mo_{0.5}W_{0.5}Te₂/CNT film. M.L. obtained the spherical aberration-corrected TEM images. L.Z., Z.Y., P.D., N.K., Z.-S.W. and H.-M.C. wrote the manuscript. All authors contributed to discussions.

Competing interests The authors declare no competing interests.

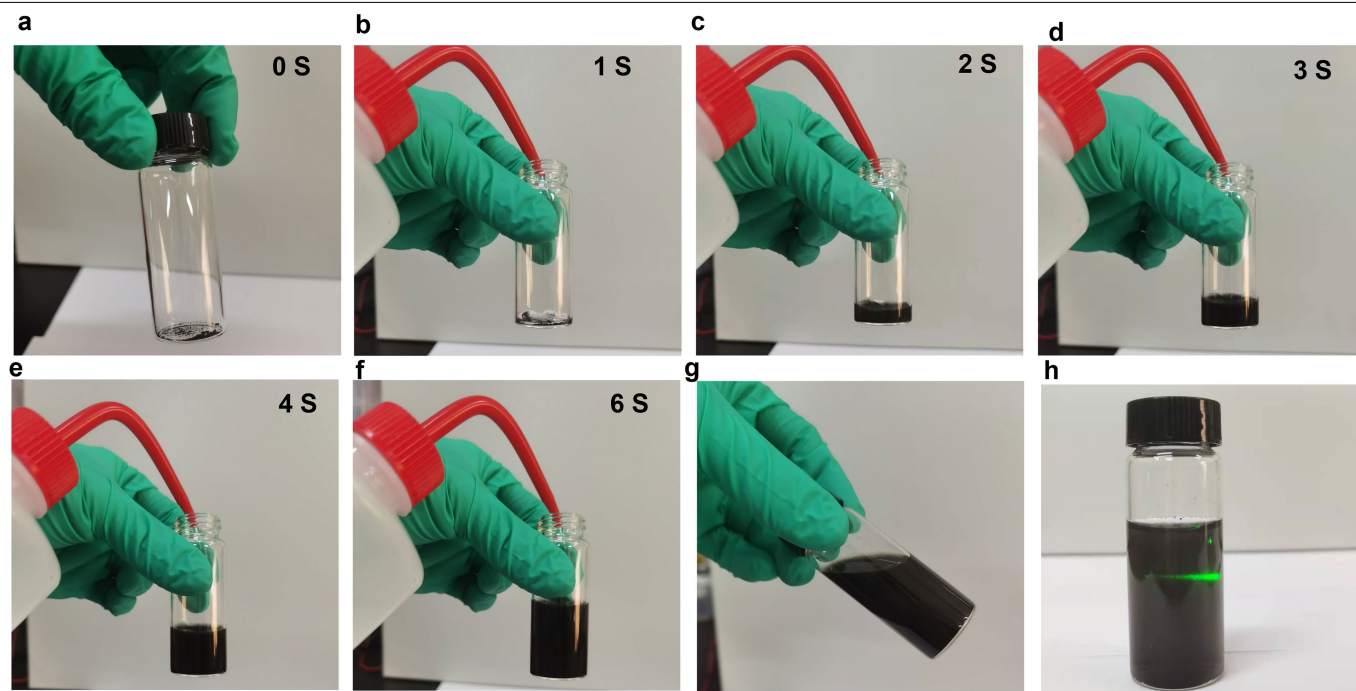
Additional information

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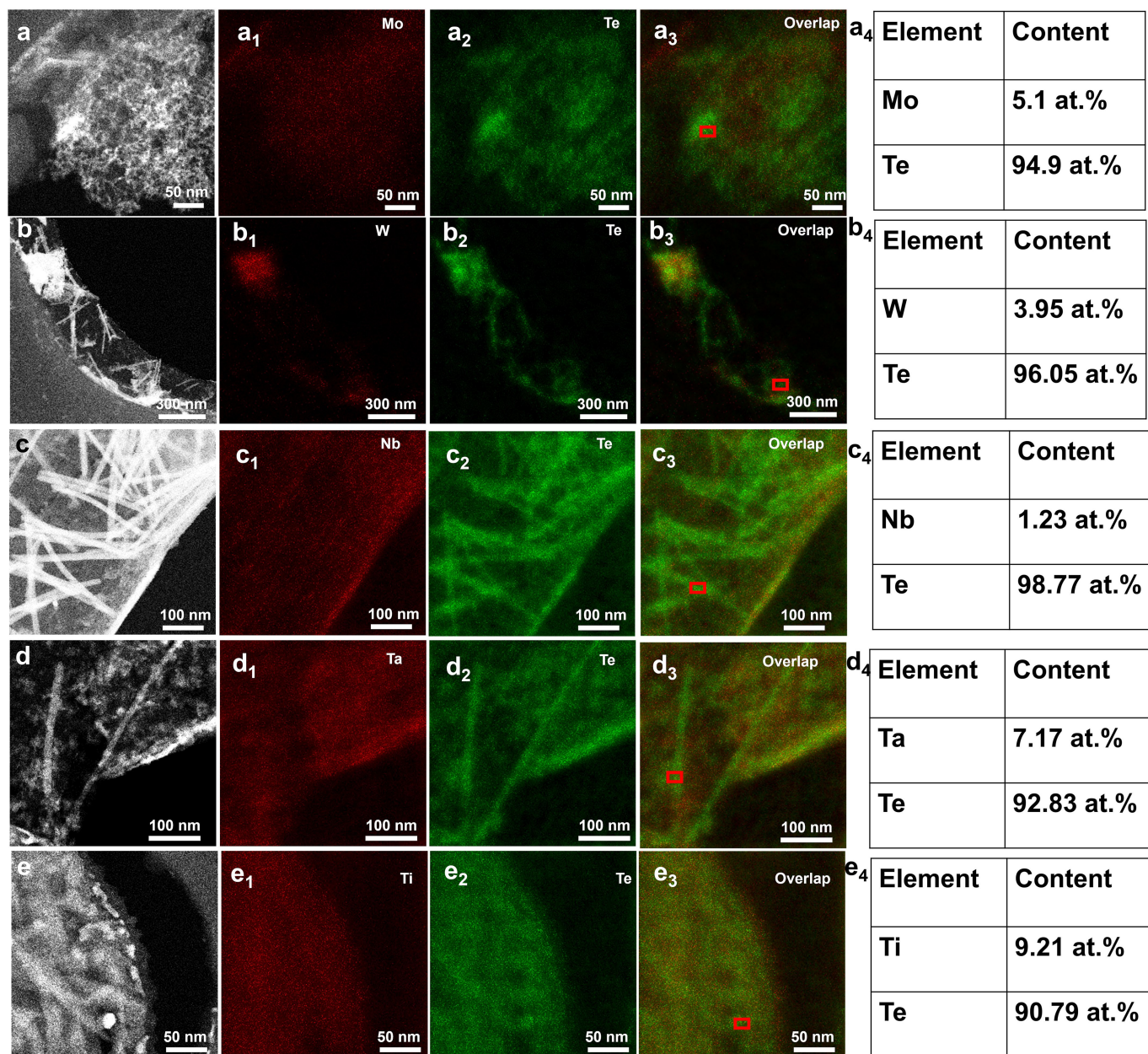
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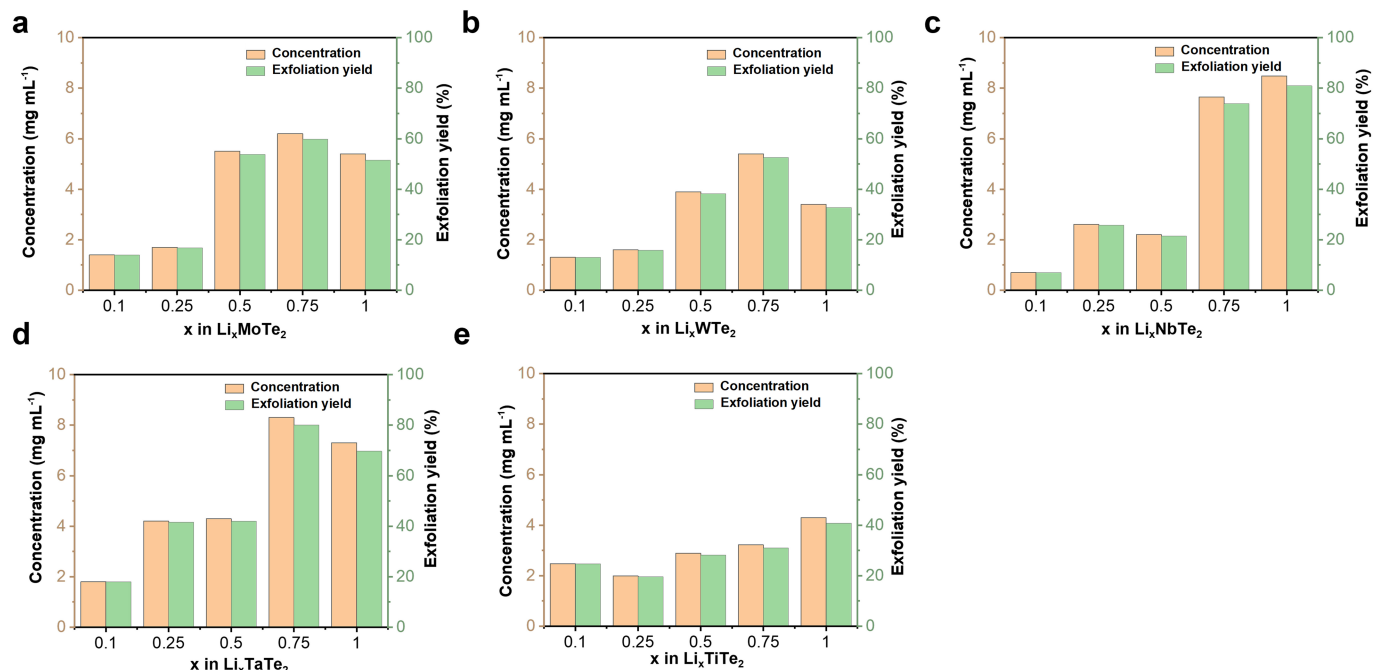
Extended Data Fig. 1 | Illustration of the hydrolysis process of lithiated NbTe_2 bulk powder into a nanosheet colloid solution. a–g. Photographs of the exfoliation process of Li_xNbTe_2 by adding distilled water to the glass bottles

at different times. Li_xNbTe_2 is hydrolysed into NbTe_2 nanosheets by the generation of H_2 gas, resulting in a homogenous colloidal dispersion. **h**, Tyndall effect of a NbTe_2 nanosheet colloid solution.



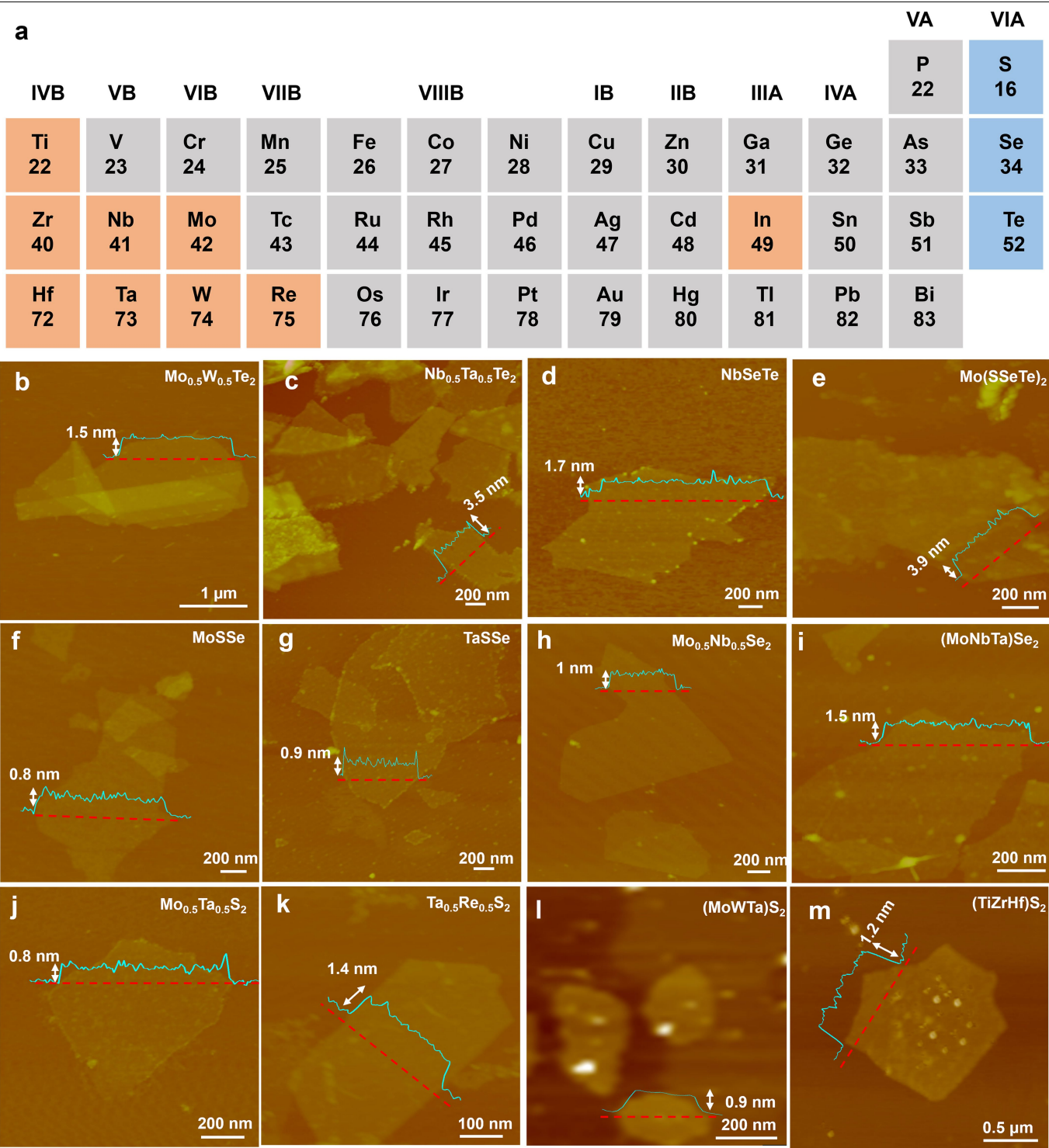
Extended Data Fig. 2 | Morphology and elemental characterization of various TMT nanosheets using a long lithium intercalation time when the molar ratio of LiBH₄ to MTe₂ is equal to 1. a–a₄, MoTe₂ nanosheets after lithium intercalation for 24 h. **a, HAADF-STEM image. EDS elemental maps of Mo (**a₁**), Te (**a₂**) and mixed Mo and Te (**a₃**). **a₄**, Table of the elemental content of the marked area in **a₃**. **b–b₄**, WTe₂ nanosheets after lithium intercalation for 6 h. **b**, HAADF-STEM image. EDS elemental maps of W (**b₁**), Te (**b₂**) and mixed W and Te (**b₃**). **b₄**, Table of the elemental content of the marked area in **b₃**. **c–c₄**, NbTe₂ nanosheets after lithium intercalation for 24 h. **c**, HAADF-STEM image. EDS elemental maps of Nb (**c₁**), Te (**c₂**) and mixed Nb and Te (**c₃**). **c₄**, Table of the**

elemental content of the marked area in **c₃**. **d–d₄**, TaTe₂ nanosheets after lithium intercalation for 6 h. **d**, HAADF-STEM image. EDS elemental maps of Ta (**d₁**), Te (**d₂**) and mixed Ta and Te (**d₃**). **d₄**, Table of the elemental content of the marked area in **d₃**. **e–e₄**, TiTe₂ nanosheets after lithium intercalation for 6 h. **e**, HAADF-STEM image. EDS elemental maps of Ti (**e₁**), Te (**e₂**) and mixed Ti and Te (**e₃**). **e₄**, Table of the elemental content of the marked area in **e₃**. The HAADF-STEM EDS elemental maps show that the morphology of the decomposition products is a nanobelt and that Te is present in all samples after a long lithium intercalation time.



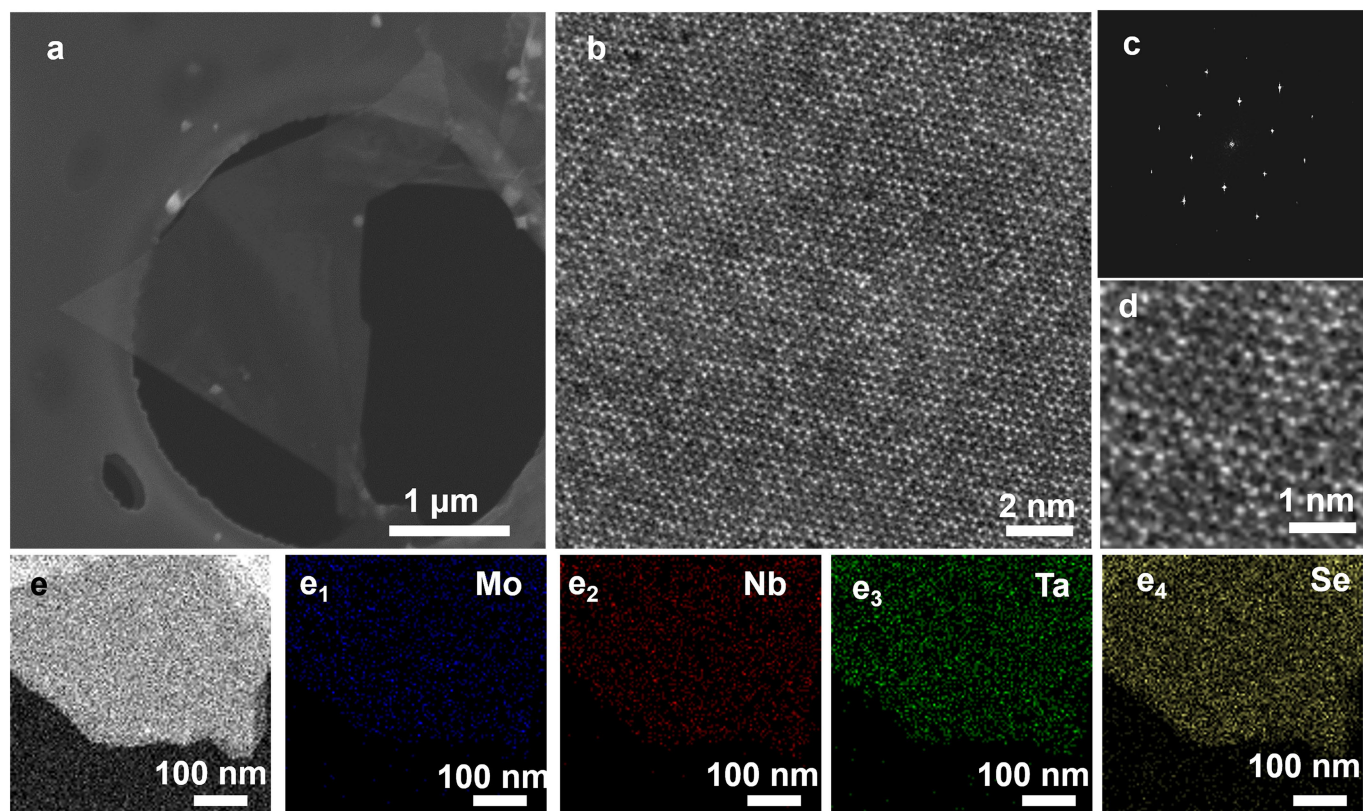
Extended Data Fig. 3 | The influence of LiBH_4 content on exfoliation yield and solution concentration. **a**, MoTe_2 nanosheets. **b**, WTe_2 nanosheets. **c**, NbTe_2 nanosheets. **d**, TaTe_2 nanosheets. **e**, TiTe_2 nanosheets. We found that molar

ratios of LiBH_4 to MTe_2 ranging from 0.75 to 1 are suitable for achieving a high exfoliation yield of more than 60% for MoTe_2 , 50% for WTe_2 , 80% for NbTe_2 , 80% for TaTe_2 and 40% for TiTe_2 .

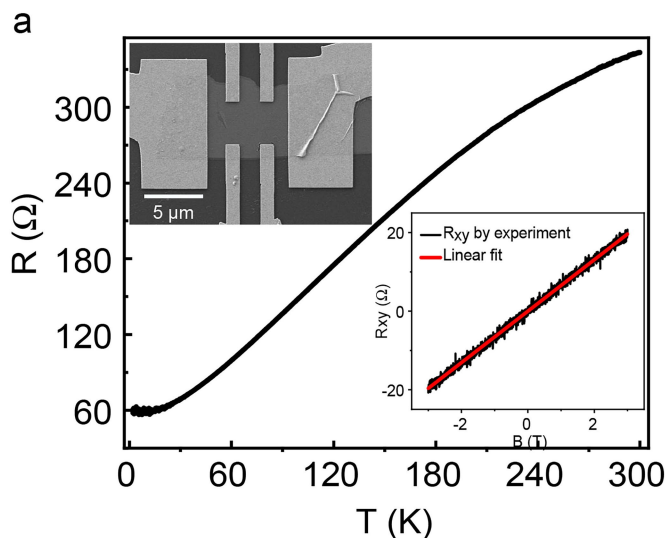


Extended Data Fig. 4 | Summary of synthesizable materials using solid lithiation and exfoliation. a, Periodic table showing the metals (highlighted in brown) and chalcogens (highlighted in blue) that have the possibility of forming layered sulfides, selenides and tellurides. **b–m**, AFM images and

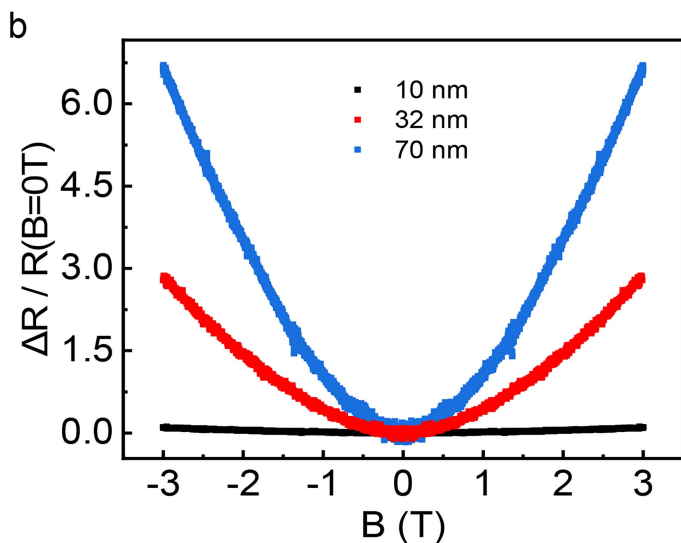
height profiles (insets) of 12 types of telluride, selenide and sulfide nanosheet. **b**, $\text{Mo}_{0.5}\text{W}_{0.5}\text{Te}_2$. **c**, $\text{Nb}_{0.5}\text{Ta}_{0.5}\text{Te}_2$. **d**, NbSeTe . **e**, $\text{Mo}(\text{SSeTe})_2$. **f**, MoSSe . **g**, TaSSe . **h**, $\text{Mo}_{0.5}\text{Nb}_{0.5}\text{Se}_2$. **i**, $(\text{MoNbTa})\text{Se}_2$. **j**, $\text{Mo}_{0.5}\text{Ta}_{0.5}\text{S}_2$. **k**, $\text{Ta}_{0.5}\text{Re}_{0.5}\text{S}_2$. **l**, $(\text{MoWTa})\text{S}_2$. **m**, $(\text{TiZrHf})\text{S}_2$.



Extended Data Fig. 5 | Structural characterizations of a $(\text{MoNbTa})\text{Se}_2$ nanosheet. **a**, Low-magnification STEM image. **b**, Atomic-resolution HAADF-STEM image. **c**, FFT pattern. **d**, Magnified HAADF-STEM image of **b**. **e–e₄**, HAADF-STEM image and EDS elemental maps of Mo, Nb, Ta and Se.



Extended Data Fig. 6 | Transport properties of a $\text{Mo}_{0.5}\text{W}_{0.5}\text{Te}_2$ nanosheet.
a, Low-temperature transport measurement of a $\text{Mo}_{0.5}\text{W}_{0.5}\text{Te}_2$ thin nanosheet. The temperature dependence of resistance shows metallic behaviour. Upper inset, SEM image of a fabricated device with multiterminal Hall-bar geometry. Lower inset, the Hall measurement shows a carrier density of $9.6 \times 10^{13} \text{ cm}^{-2}$.



b, Magnetoresistance, defined as $(R(B) - R(B=0))/R(B=0)$, plotted as a function of magnetic field for $\text{Mo}_{0.5}\text{W}_{0.5}\text{Te}_2$ thin films with thicknesses ranging from 10 to 70 nm. It is seen that the positive magnetoresistance is substantially decreased with decreasing thickness.